



# IRP1608W11-B00

## SMD Type 940nm Infrared Emitter

### Features

- Small double-end package
- Viewing Angle at X axis (Note3) =  $\pm 50^\circ$
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

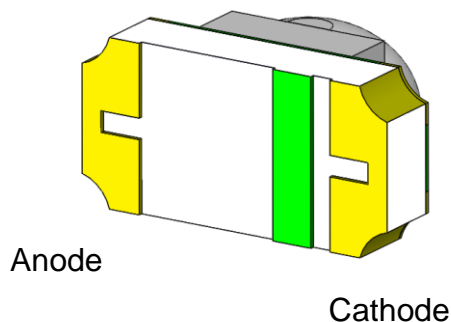
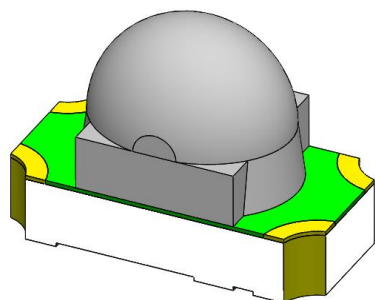
### Applications

- Infrared sensor

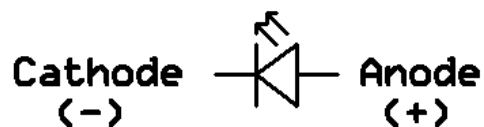
### Description

The IRP1608W11-B00 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 940nm LED spectrally matched with phototransistor or photodiode.

### Package Outline



### Schematic





# IRP1608W11-B00

## SMD Type 940nm Infrared Emitter

### Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
$I_F$	Continuous Forward Current	70	mA	
$I_{FP}$	Peak Forward Current	0.7	A	1
$V_R$	Reverse Voltage	5	V	
$T_{opr}$	Operating Temperature	-40 ~ +85	°C	
$T_{stg}$	Storage Temperature	-40 ~ +100	°C	
$T_{sol}$	Soldering Temperature	260	°C	2
$P_D$	Power Dissipation at(or below) 25°C Free Air Temperature	119	mW	

### Electro-Optical Characteristics $T_A = 25^\circ\text{C}$ (unless otherwise specified)

#### Optical Characteristics

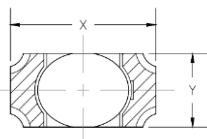
Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$I_e$	Radiant Intensity	$I_F=20\text{mA}$	2.5	5.0	8.0	mW/sr	
		$I_F=70\text{mA}$	-	17	-		
$\lambda_p$	Peak Wavelength	$I_F=20\text{mA}$	-	940	-	nm	
$\Delta\lambda$	Spectral Bandwidth	$I_F=20\text{mA}$	-	40	-	nm	
$\theta_{1/2}$	Angle of Half Intensity (X)	$I_F=20\text{mA}$	-	$\pm 50$	-	deg	3
	Angle of Half Intensity (Y)		-	$\pm 35$	-		

#### Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Typ	Max	Units	Notes
$V_F$	Forward Voltage	$I_F=20\text{mA}$	1.1	1.3	1.6	V	
		$I_F=70\text{mA}$	1.2	1.45	1.7		
$I_R$	Reverse Current	$V_R=5\text{V}$	-	-	10	$\mu\text{A}$	

#### Notes:

- $I_{FP}$  Conditions--Pulse Width  $\leq 100\mu\text{s}$  and Duty  $\leq 1\%$ .
- Soldering time  $\leq 5$  seconds
- Test condition :

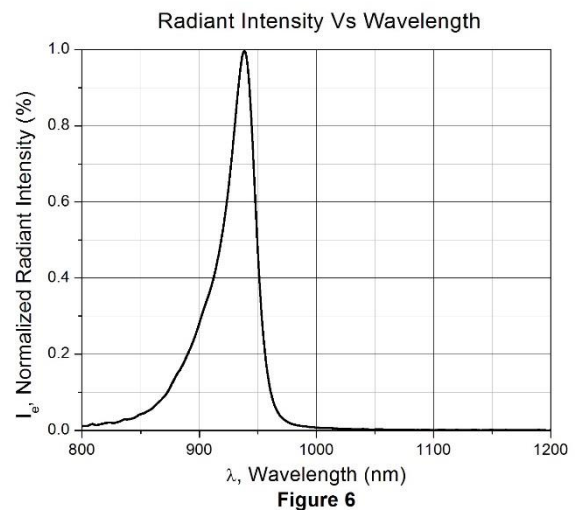
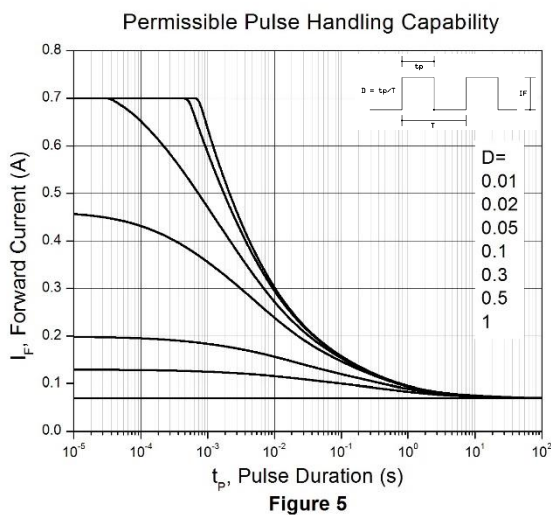
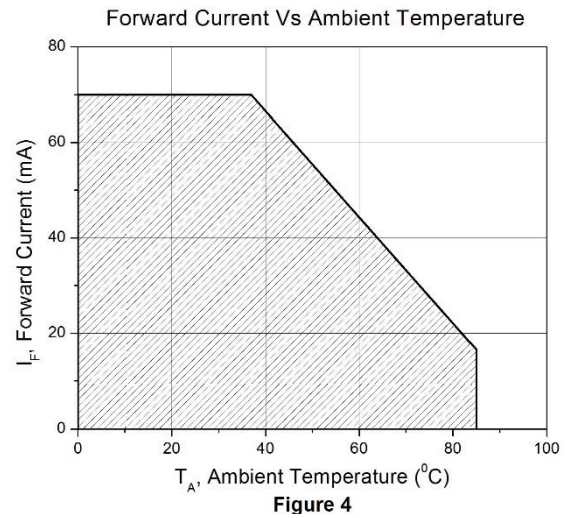
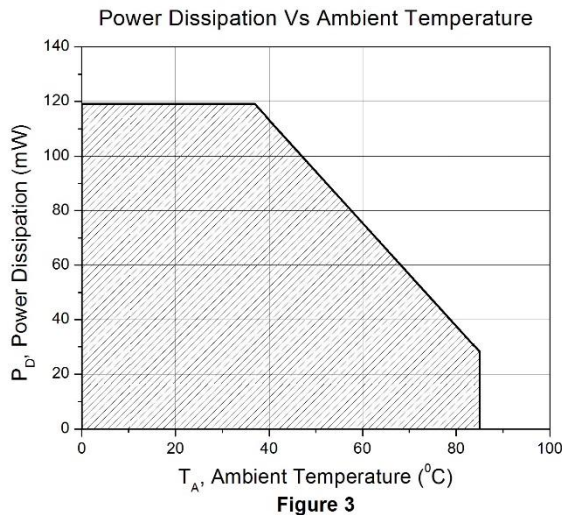
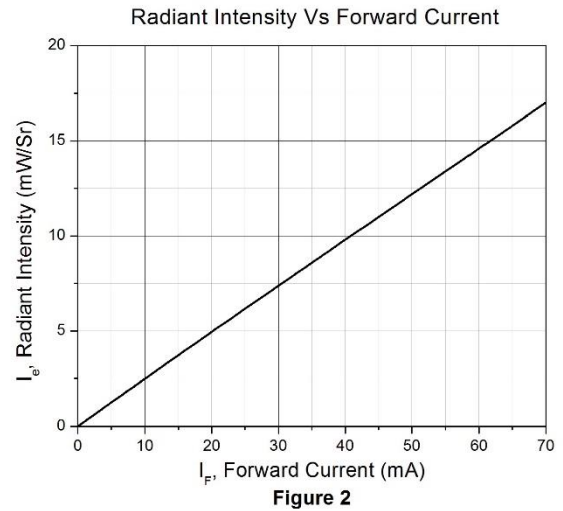
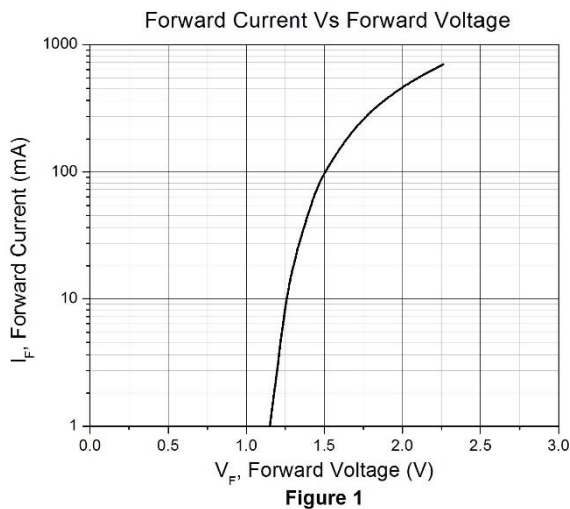




# IRP1608W11-B00

## SMD Type 940nm Infrared Emitter

### Typical Characteristic Curves





### Typical Characteristic Curves

Angular Displacement at X axis

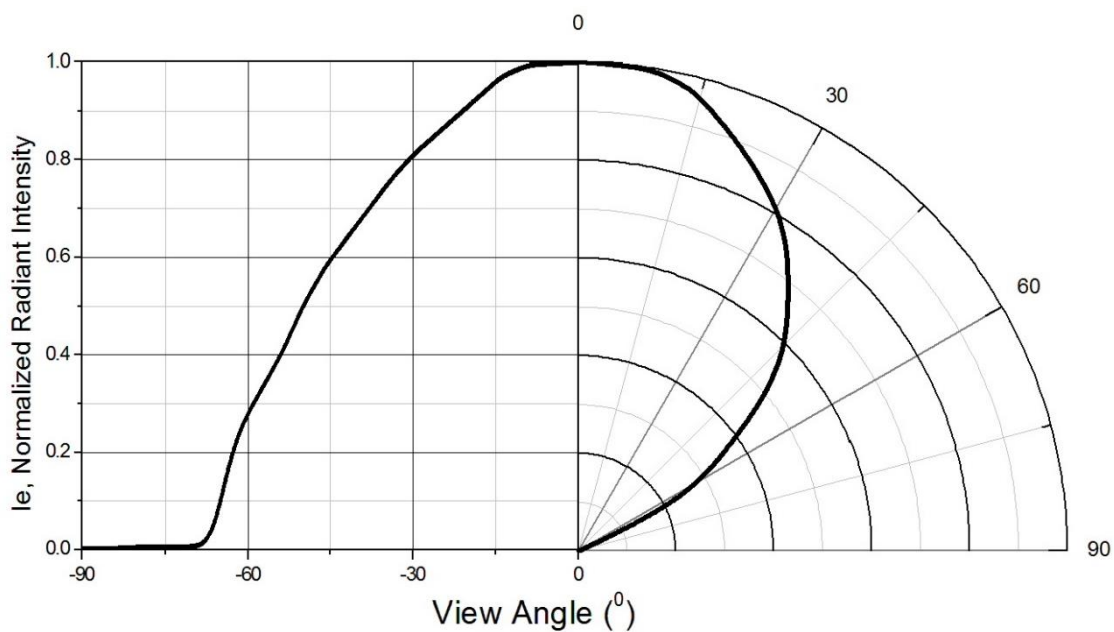


Figure 7

Angular Displacement at Y axis

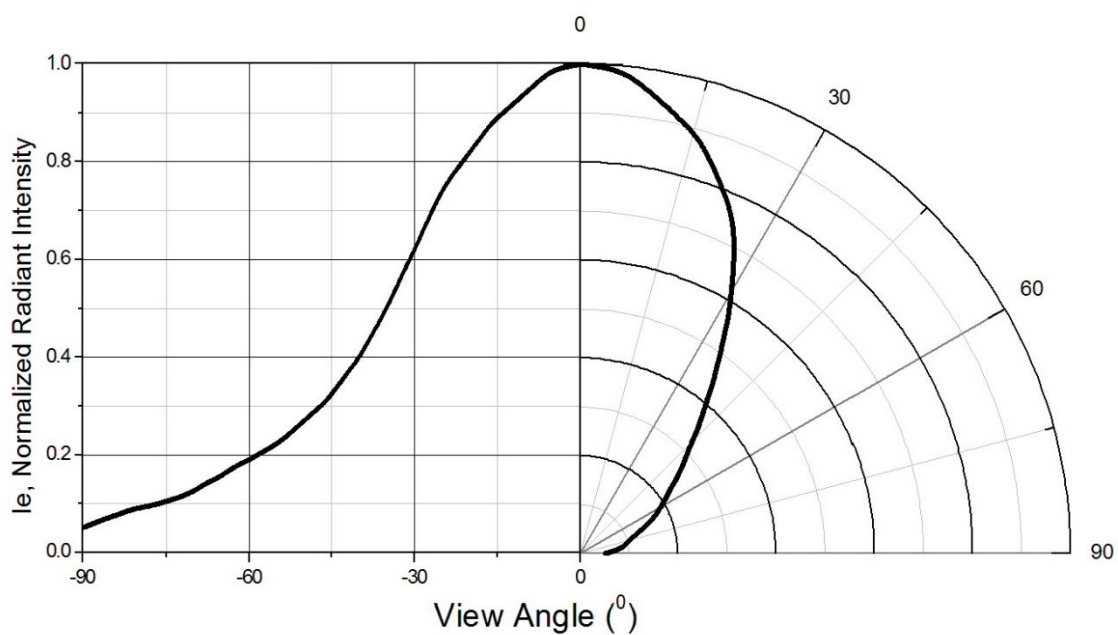
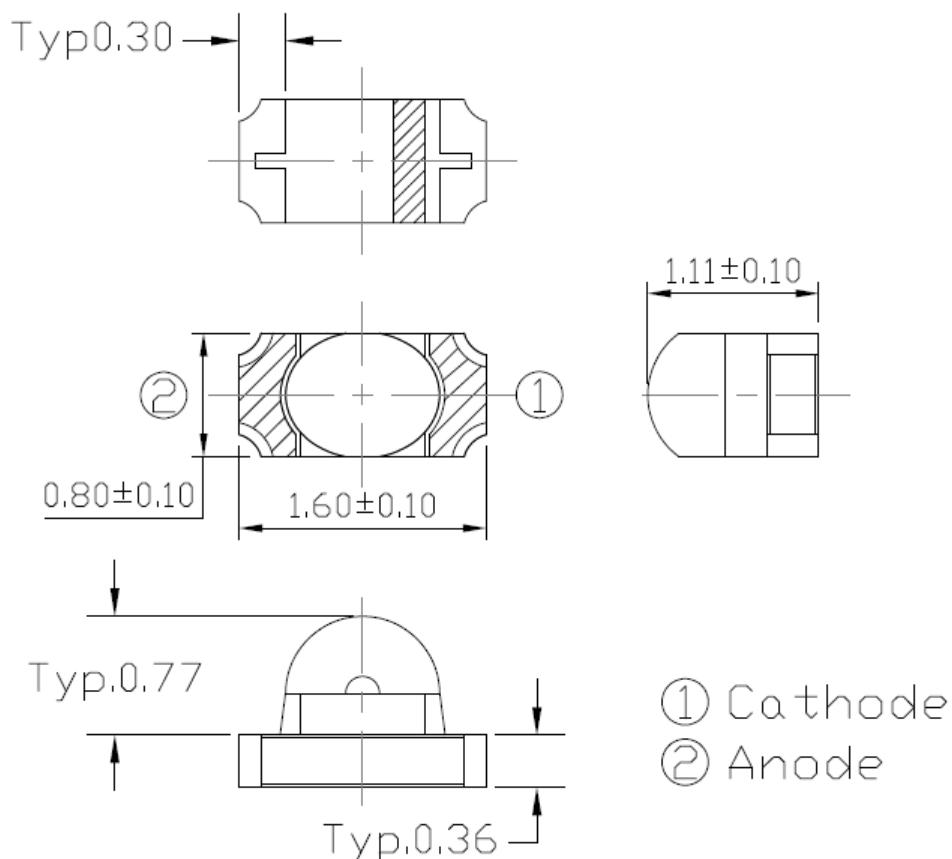


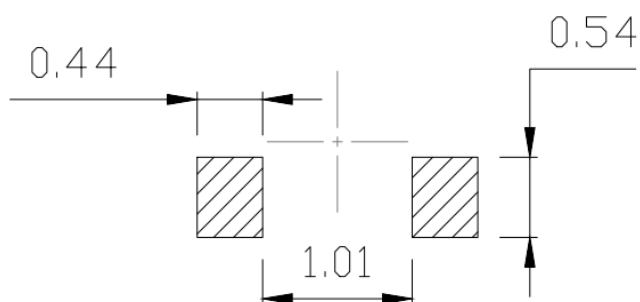
Figure 8



**Package Dimension** *All dimensions are in mm, unless otherwise stated*



**Recommended Soldering Mask** *All dimensions are in mm, unless otherwise stated*



**Ordering Information**

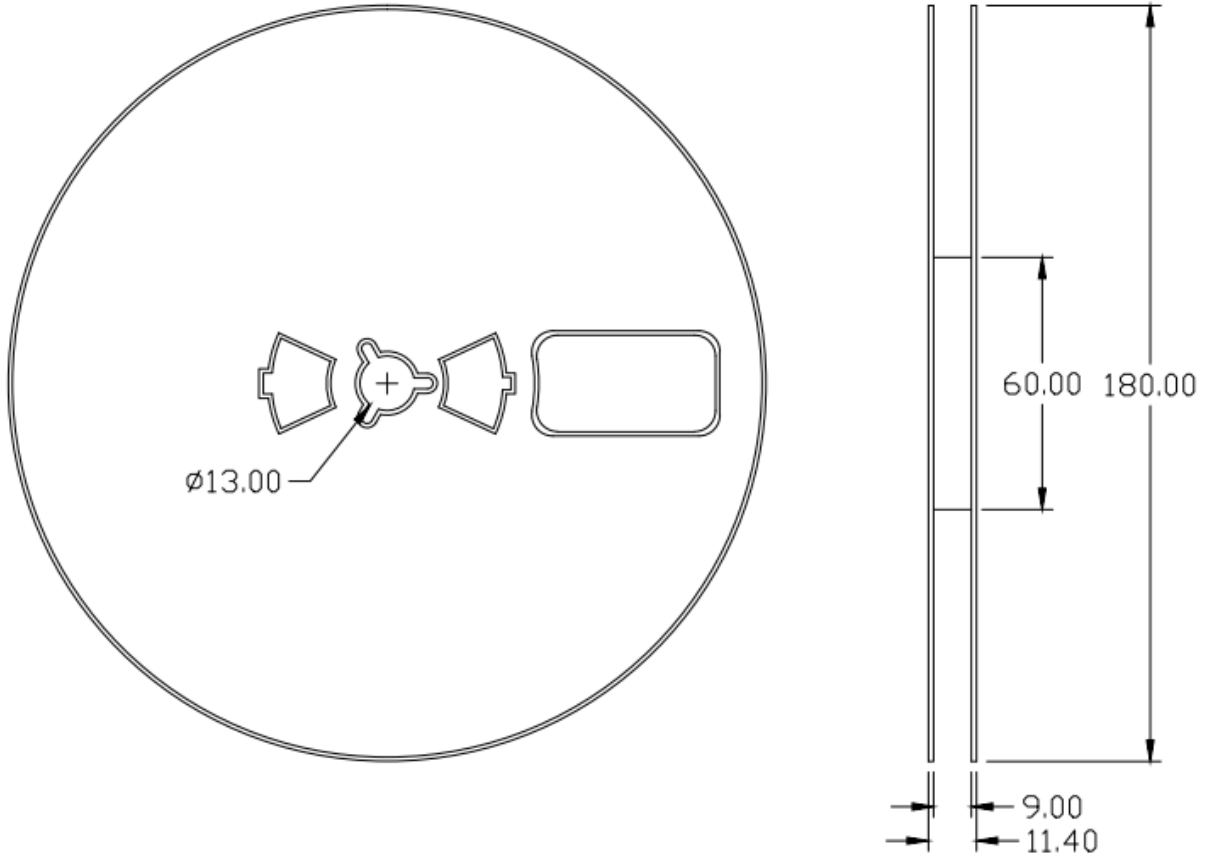
Part Number	Description	Quantity
IRP1608W11-B00	Tape & Reel	3000 pcs



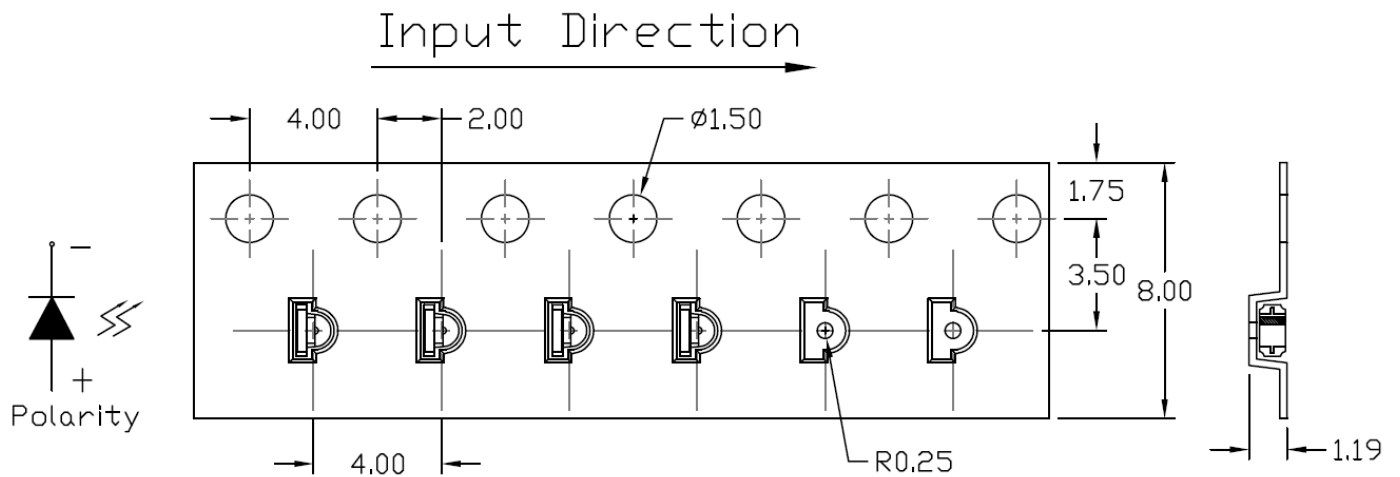
# IRP1608W11-B00

## SMD Type 940nm Infrared Emitter

### Reel Dimension *All dimensions are in mm, unless otherwise stated*



### Tape Dimension *All dimensions are in mm, unless otherwise stated*

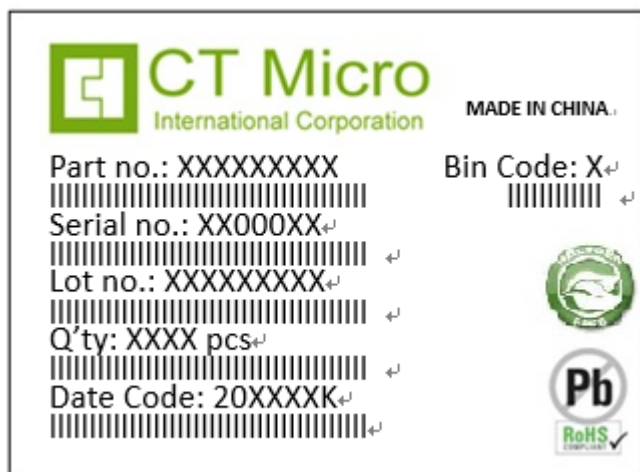




IRP1608W11-B00

SMD Type 940nm Infrared Emitter

## Label Form Specification



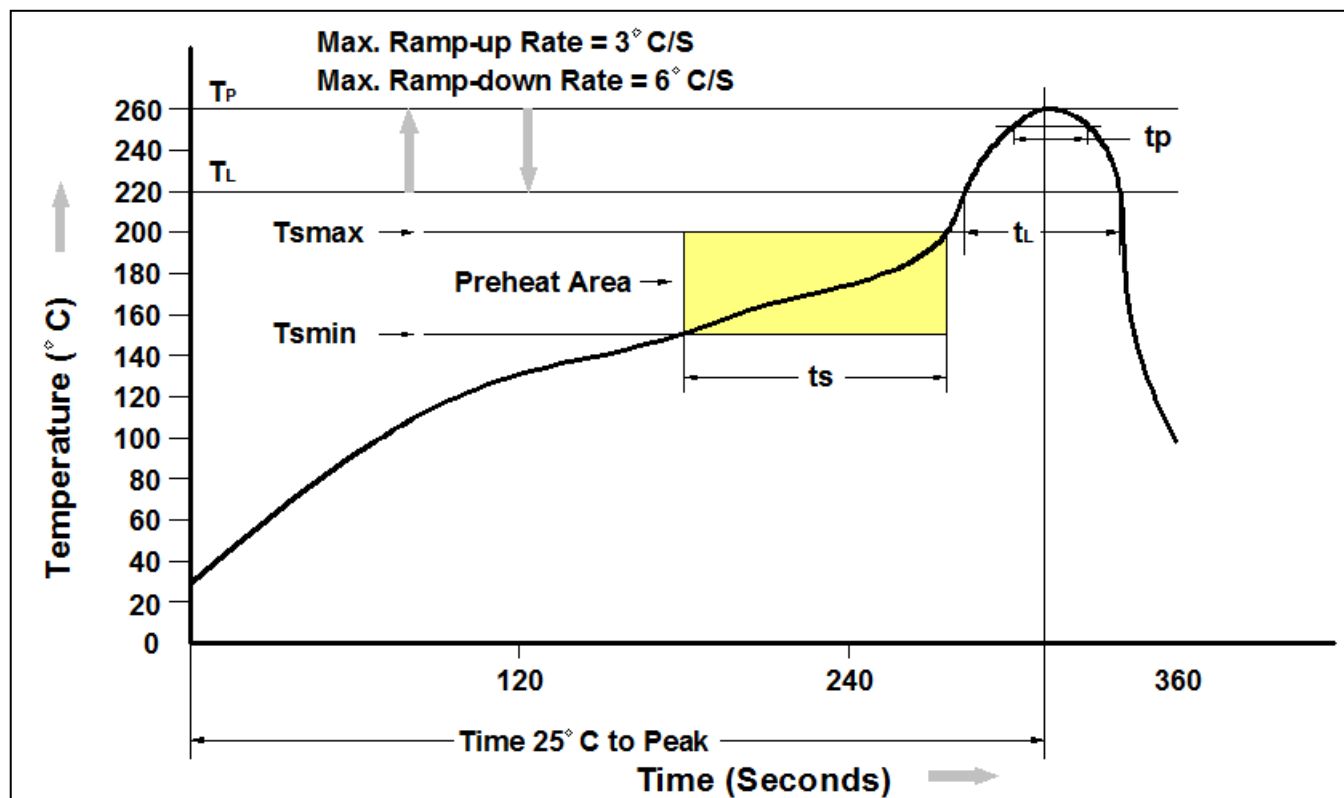
Part no: CTM Production Number  
Serial no: Production Number  
Lot no: Lot number  
Q'ty: Packing Quantity  
Date Code: Manufacture Date  
Bin Code: 1e Ranks  
MADE IN CHINA: Production Place

## Storage Condition

1. Do not open moisture proof bag before the products are ready to use.
2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening.  
Shelf life of non-opened bag is 12 months after the bag sealing date.
3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.



## Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (T <sub>smin</sub> )	150°C
Temperature Max. (T <sub>smax</sub> )	200°C
Time (t <sub>s</sub> ) from (T <sub>smin</sub> to T <sub>smax</sub> )	60-120 seconds
Ramp-up Rate (t <sub>L</sub> to t <sub>P</sub> )	3°C/second max.
Liquidous Temperature (T <sub>L</sub> )	217°C
Time (t <sub>L</sub> ) Maintained Above (T <sub>L</sub> )	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t <sub>P</sub> ) within 5°C of 260°C	30 seconds
Ramp-down Rate (T <sub>P</sub> to T <sub>L</sub> )	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.





# IRP1608W11-B00

## SMD Type 940nm Infrared Emitter

---

### DISCLAIMER

CT MICRO RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. CT MICRO DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

---

CT MICRO ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT EXPRESS WRITTEN APPROVAL OF CT MICRO INTERNATIONAL CORPORATION.

- 1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instruction for use provided in the labelling, can be reasonably expected to result in significant injury to the user.*
- 2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.*